

TYN16Y-600CTF

Rev.01 - 07 February 2022

SCR

Product data sheet

1. General description

Planar passivated Silicon Controlled Rectifier (SCR) in a IITO220 package intended for use in applications requiring good bidirectional blocking voltage and high surge current capability and high junction temperature capability ($T_{i(max)} = 150$ °C).

2. Features and benefits

- High junction operating temperature capability (T_{i(max)} = 150 °C)
- High bidirectional blocking voltage capability
- Very high current surge capability
- · High thermal cycling performance
- · Planar passivated for voltage ruggedness and reliability
- Internally insulated package
- Isolated mounting base with 2500 $V_{(\text{RMS})}$ isolation

3. Applications

- Capacitive Discharge Ignition (CDI)
- Crowbar protection
- Inrush protection
- Motor control
- Voltage regulation

4. Quick reference data

Symbol	Doromotor	Conditions	Min	Tun	Max	Unit
Symbol	Parameter	Conditions	IVITI	Тур	wax	Unit
V_{DRM}	repetitive peak off-state voltage		-	-	600	V
$I_{T(RMS)}$	RMS on-state current	half sine wave; T _{mb} ≤ 118 °C; <u>Fig. 1; Fig. 2; Fig. 3</u>	-	-	16	А
I _{TSM}	non-repetitive peak on- state current	half sine wave; T _{j(init)} = 25 °C; t _p = 10 ms; <u>Fig. 4;</u> <u>Fig. 5</u>	-	-	188	А
		half sine wave; $T_{j(init)}$ = 25 °C; t_p = 8.3 ms	-	-	207	А
Tj	junction temperature		-	-	150	°C
Static ch	aracteristics					·
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 7</u>	5	-	10	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	-	40	mA
V _T	on-state voltage	$I_{T} = 16 \text{ A}; T_{j} = 25 \text{ °C}; Fig. 10$	-	-	1.6	V
Dynamic	characteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 402 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit	400	-	-	V/µs

5. Pinning information

Simplified outline	Graphic symbol
mb	
	A H K G
	sym037

6. Ordering information

Table 3. Ordering	information
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Type number	Package Name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
TYN16Y-600CTF	IITO220	TYN16Y-600CTFQ	Tube	50	SOT78D	10-July-2007

7. Marking

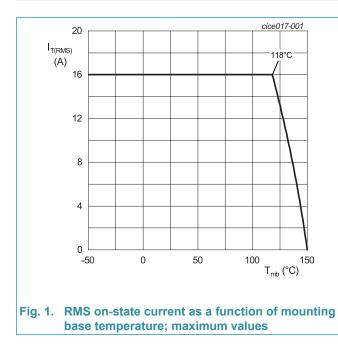
Table 4. Marking codes	
Type number	Marking codes
TYN16Y-600CTF	TYN16Y 600CTF

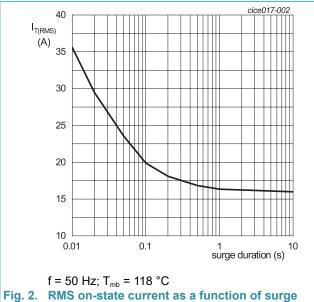
8. Limiting values

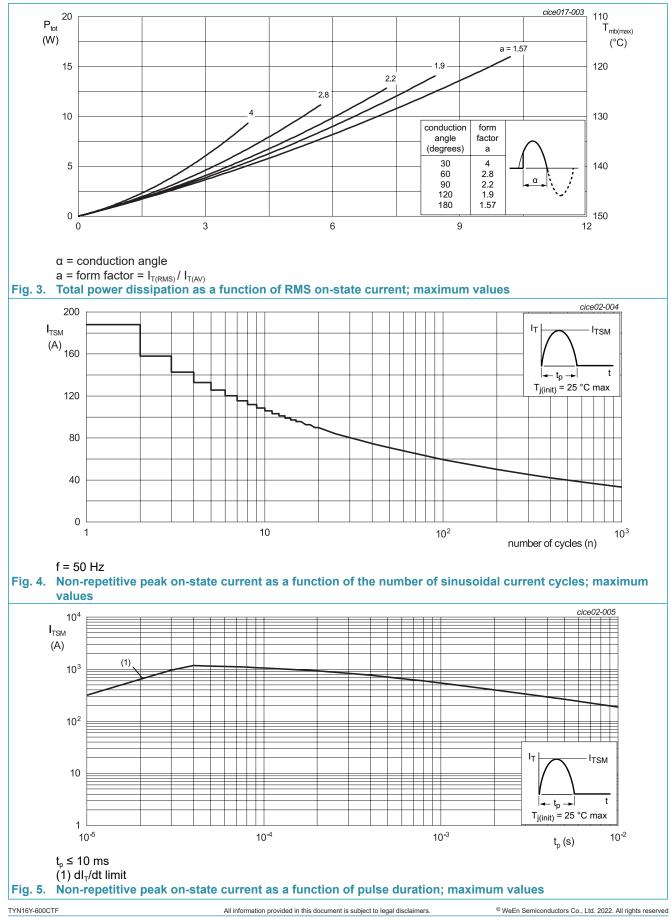
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DRM}	repetitive peak off-state voltage		-	600	V
V _{RRM}	repetitive peak reverse voltage		-	600	V
I _{T(AV)}	average on-state current	half sine wave; $T_{mb} \le 118 \text{ °C}$;	-	10.2	А
$I_{T(RMS)}$	RMS on-state current	half sine wave; T _{mb} ≤ 118 °C; Fig. 1; Fig. 2; Fig. 3	-	16	A
I _{TSM}	non-repetitive peak on- state current	half sine wave; $T_{j(init)}$ = 25 °C; t_p = 10 ms; Fig. 4; Fig. 5	-	188	A
		half sine wave; $T_{j(init)}$ = 25 °C; t_p = 8.3 ms	-	207	А
l ² t	l ² t for fusing	t _p = 10 ms; sine-wave pulse	-	177	A ² s
dl _T /dt	rate of rise of on-state current	I _G = 20 mA	-	100	A/µs
I _{GM}	peak gate current		-	4	А
V_{GM}	peak gate voltage		-	5	V
P _{GM}	peak gate power		-	10	W
P _{G(AV)}	average gate power	over any 20 ms period	-	1	W
T _{stg}	storage temperature		-40	150	°C
T _i	junction temperature		-	150	°C

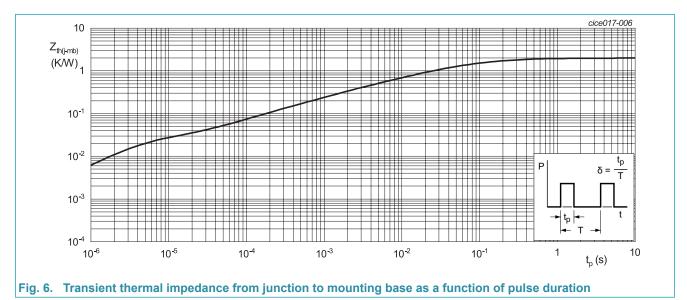






9. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	<u>Fig. 6</u>	-	-	2	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	-	60	-	K/W

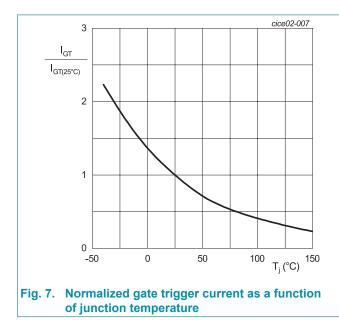


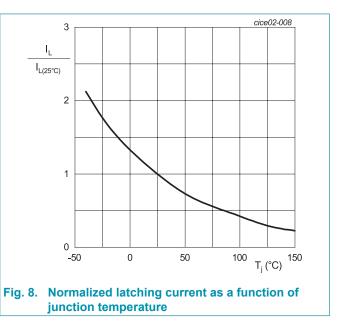
10. Isolation characteristics

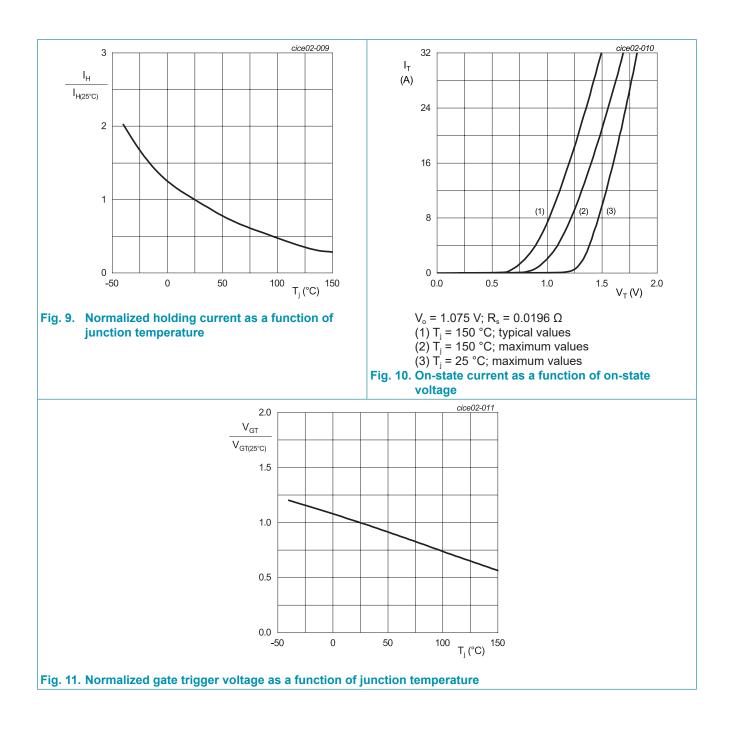
Table 7. Isolation characteristics							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$V_{\text{isol}(\text{RMS})}$	RMS isolation voltage	50 Hz \leq f \leq 60 Hz; RH \leq 65 %; from all pins to external heatsink; sinusoidal waveform; clean and dust free		-	-	2500	V
C _{isol}	isolation capacitance	from cathode to external heatsink		-	10	-	pF

11. Characteristics

Table 8. Cl	naracteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static cha	racteristics						
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 7</u>		5	-	10	mA
I _L	latching current	V _D = 12 V; I _G = 0.1 A; T _j = 25 °C; <u>Fig. 8</u>		-	-	60	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>		-	-	40	mA
V _T	on-state voltage	I _T = 16 A; T _j = 25 °C; <u>Fig. 10</u>		-	-	1.6	V
V _{GT} gate trigge	gate trigger voltage	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 11</u>		-	0.8	1	V
		V _D = 400 V; I _T = 0.1 A; T _j = 125 °C		0.25	0.45	-	V
V _{GR}	gate reverse voltage	I _{RG} = 100 mA		10	-	-	V
I _D	off-state current	V _D = 600 V; T _j = 25 °C		-	-	10	μA
		V _D = 600 V; T _j = 150 °C		-	-	2	mA
I _R	reverse current	V _D = 600 V; T _j = 25 °C		-	-	10	μA
		V _D = 600 V; T _j = 150 °C		-	-	2	mA
Dynamic	characteristics		· ·				
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 402 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit		400	-	-	V/µs
t _{gt}	gate-controlled turn-on time	$I_{TM} = 16 \text{ A}; V_D = 600 \text{ V}; I_G = 20 \text{ mA};$ $dI_G/dt = 5 \text{ A}/\mu\text{s}; T_j = 25 \text{ °C}$		-	2	-	μs
t _q	commutated turn-off time	$I_{\rm TM}$ = 2 A; $t_{\rm p}$ = 50 µs; dV/dt = 5 V/µs; dI/dt = 30 A/µs		-	-	12	μs

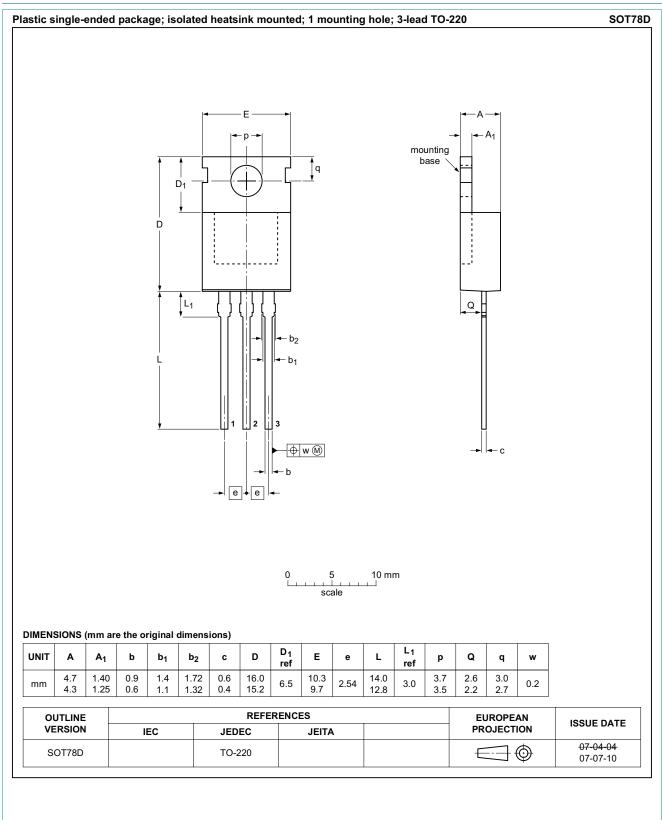








12. Package outline



TYN16Y-600CTF Product data sheet

13. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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